

74ACTQ823

Quiet Series™ 9-Bit D-Type Flip-Flop with 3-STATE Outputs

General Description

The ACTQ823 is a 9-bit buffered register. It features Clock Enable and Clear which are ideal for parity bus interfacing in high performance microprogramming systems. The ACTQ823 utilizes Fairchild Quiet Series™ technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

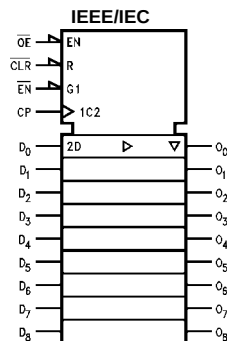
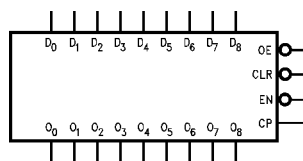
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Inputs and outputs on opposite sides of package allow easy interface with microprocessors
- Improved latch-up immunity
- TTL compatible inputs

Ordering Code:

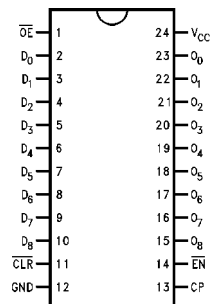
Order Number	Package Number	Package Description
74ACTQ823SC	M24B	24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74ACTQ823SPC	N24C	24-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering form.

Logic Symbols



Connection Diagram



Pin Descriptions

Pin Names	Description
D ₀ -D ₈	Data Inputs
Q ₀ -Q ₈	Data Outputs
$\overline{OE}$	Output Enable
$\overline{CLR}$	Clear
CP	Clock Input
EN	Clock Enable

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Functional Description

The ACTQ823 consists of nine D-type edge-triggered flip-flops. These have 3-STATE outputs for bus systems organized with inputs and outputs on opposite sides. The buffered clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}$ LOW, the contents of the flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops. In addition to the Clock and Output

Enable pins, there are Clear ($\overline{CLR}$) and Clock Enable ($\overline{EN}$) pins. These devices are ideal for parity bus interfacing in high performance systems.

When $\overline{CLR}$ is LOW and $\overline{OE}$ is LOW, the outputs are LOW. When $\overline{CLR}$ is HIGH, data can be entered into the flip-flops. When $\overline{EN}$ is LOW, data on the inputs is transferred to the outputs on the LOW-to-HIGH clock transition. When the $\overline{EN}$ is HIGH, the outputs do not change state, regardless of the data or clock input transitions.

Function Table

Inputs					Internal	Output	Function
$\overline{OE}$	$\overline{CLR}$	$\overline{EN}$	CP	D	Q	O	
H	X	L	↗	L	L	Z	High Z
H	X	L	↗	H	H	Z	High Z
H	L	X	X	X	L	Z	Clear
L	L	X	X	X	L	L	Clear
H	H	H	X	X	NC	Z	Hold
L	H	H	X	X	NC	NC	Hold
H	H	L	↗	L	L	Z	Load
H	H	L	↗	H	H	Z	Load
L	H	L	↗	L	L	L	Load
L	H	L	↗	H	H	H	Load

H = HIGH Voltage Level

L = LOW Voltage Level

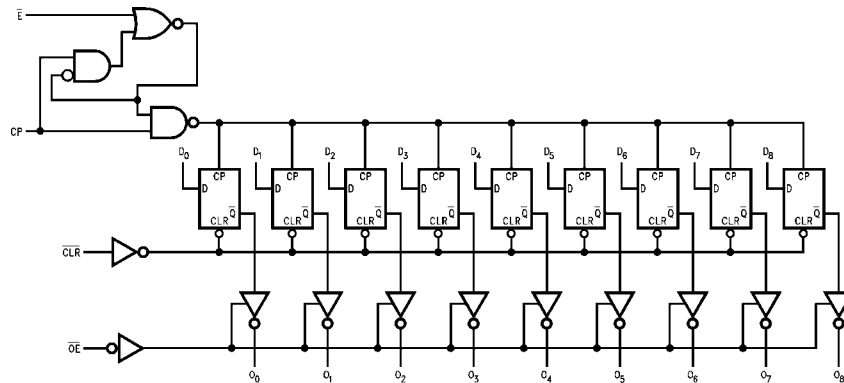
X = Immaterial

Z = High Impedance

↗ = LOW-to-HIGH Transition

NC = No Change

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC})	–0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	–20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	–0.5V to $V_{CC} + 0.5V$
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	–0.5V to $V_{CC} + 0.5V$
DC Output Source	
or Sink Current (I_O)	± 50 mA
DC V_{CC} or Ground Current	
per Output Pin (I_{CC} or I_{GND})	± 50 mA
Storage Temperature (T_{STG})	–65°C to +150°C
DC Latch-Up Source	
or Sink Current	± 300 mA
Junction Temperature (T_J)	
PDIP	140°C

Recommended Operating Conditions

Supply Voltage (V_{CC})	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	–40°C to +85°C
Minimum Input Edge Rate $\Delta V/\Delta t$	125 mV/ns
V_{IN} from 0.8V to 2.0V	
V_{CC} @ 4.5V, 5.5V	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation of FACT™ circuits outside databook specifications.

DC Electrical Characteristics for ACTQ

Symbol	Parameter	V _{CC} (V)	T _A = +25°C		T _A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits				
V _{IH}	Minimum HIGH Level Input Voltage	4.5	1.5	2.0	2.0		V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		5.5	1.5	2.0	2.0			
V _{IL}	Maximum LOW Level Input Voltage	4.5	1.5	0.8	0.8		V	V _{OUT} = 0.1V or V _{CC} − 0.1V
		5.5	1.5	0.8	0.8			
V _{OH}	Minimum HIGH Level Output Voltage	4.5	4.49	4.4	4.4		V	I _{OUT} = −50 μA
		5.5	5.49	5.4	5.4			
		4.5		3.86	3.76		V	V _{IN} = V _{IL} or V _{IH} I _{OH} = −24 mA I _{OH} = −24 mA (Note 2)
		5.5		4.86	4.76			
V _{OL}	Maximum LOW Level Output Voltage	4.5	0.001	0.1	0.1		V	I _{OUT} = 50 μA
		5.5	0.001	0.1	0.1			
		4.5		0.36	0.44		V	V _{IN} = V _{IL} or V _{IH} I _{OL} = 24 mA I _{OL} = 24 mA (Note 2)
		5.5		0.36	0.44			
I _{IN}	Maximum Input Leakage Current	5.5		± 0.1	± 1.0		μA	V _I = V _{CC} , GND
I _{OZ}	Maximum 3-STATE Leakage Current	5.5		± 0.5	± 5.0		μA	V _I = V _{IL} , V _{IH} V _O = V _{CC} , GND
I _{CCT}	Maximum I _{CC} /Input	5.5	0.6		1.5		mA	V _I = V _{CC} − 2.1V
I _{OLD}	Minimum Dynamic	5.5			75		mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current (Note 3)	5.5			−75		mA	V _{OHD} = 3.85V Min
I _{CC}	Maximum Quiescent Supply Current	5.5		8.0	80.0		μA	V _{IN} = V _{CC} or GND
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	5.0	1.1	1.5			V	Figure 1, Figure 2 (Note 4)(Note 5)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	5.0	−0.6	−1.2			V	Figure 1, Figure 2 (Note 4)(Note 5)
V _{IHD}	Minimum HIGH Level Dynamic Input Voltage	5.0	1.9	2.2			V	(Note 4)(Note 6)

DC Electrical Characteristics for ACTQ (Continued)

Symbol	Parameter	V _{CC} (V)	T _A = +25°C		T _A = -40°C to +85°C	Units	Conditions
			Typ	Guaranteed Limits			
V _{ILD}	Maximum LOW Level Dynamic Input Voltage	5.0	1.2	0.8		V	(Note 4)(Note 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: PDIP package.

Note 5: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

Note 6: Max number of data inputs (n) switching. (n - 1) inputs switching 0V to 3V Input-under-test switching: 3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V _{CC} (V) (Note 7)	T _A = +25°C C _L = 50 pF			T _A = -40°C to +85°C C _L = 50 pF		Units
			Min	Typ	Max	Min	Max	
t _{PLH} t _{PHL}	Propagation Delay CP to O _n	5.0	2.0	7.0	9.0	2.0	10.0	ns
t _{PLH} t _{PHL}	Propagation Delay CLR to O _n	5.0	2.0	7.0	9.0	2.0	10.0	ns
t _{PZH} t _{PZL}	Output Enable Time OE to O _n	5.0	2.5	8.0	10.0	2.5	11.0	ns
t _{PHZ} t _{PLZ}	Output Disable Time OE to O _n	5.0	1.0	6.0	8.0	1.0	9.0	ns
t _{OSLH} t _{OSHL}	Output to Output Skew D _n to O _n (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is 5.0V ± 0.5V.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs within the same packaged device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design. Not tested.

AC Operating Requirements

Symbol	Parameter	V _{CC} (V) (Note 9)	T _A = +25°C C _L = 50 pF		T _A = -40°C to +85°C	Units
			Typ	Guaranteed Minimum		
t _S	Setup Time, HIGH or LOW D to CP	5.0	0.5	3.0	3.0	ns
t _H	Hold Time, HIGH or LOW D _n to CP	5.0	0	1.5	1.5	ns
t _S	Setup Time, HIGH or LOW EN to CP	5.0	0	3.0	3.0	ns
t _H	Hold Time, HIGH or LOW EN to CP	5.0	0	1.5	1.5	ns
t _W	CP Pulse Width, HIGH or LOW	5.0	2.5	4.0	4.0	ns
t _W	$\overline{\text{CLR}}$ Pulse Width, LOW	5.0	3.0	4.0		ns
t _{REC}	$\overline{\text{CLR}}$ to CP Recovery Time	5.0	1.5	3.5	4.0	ns

Note 9: Voltage Range 5.0 is 5.0V ± 0.5V

Capacitance

Symbol	Parameter	Typ	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation Capacitance	54	pF	V _{CC} = 5.0V

FACT Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

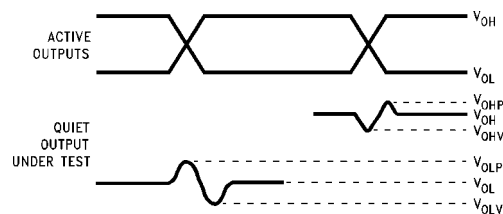
Hewlett Packard Model 8180A Word Generator

PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω.
2. Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the HFS generator channels before testing. This will ensure that the outputs switch simultaneously.
3. Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
4. Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement.



V_{OHV} and V_{OLP} are measured with respect to ground reference.

Input pulses have the following characteristics: $f = 1$ MHz, $t_r = 3$ ns, $t_f = 3$ ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

5. Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope.

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV} :

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case transition for active and enable.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD} :

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL} , until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD} .
- Next decrease the input HIGH voltage level, V_{IH} , until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD} .
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

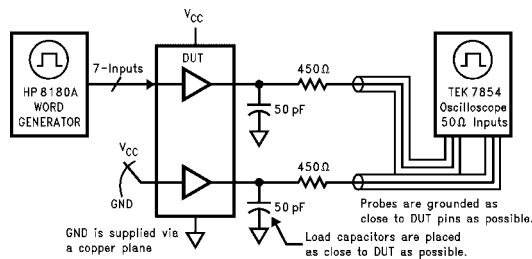
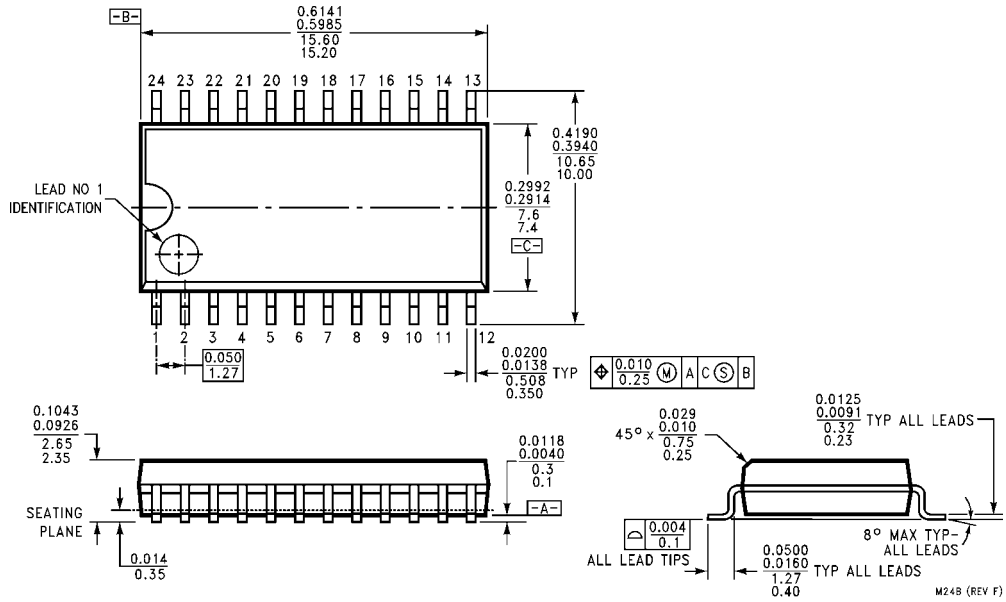


FIGURE 2. Simultaneous Switching Test Circuit

Physical Dimensions inches (millimeters) unless otherwise noted



24-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
Package Number M24B

